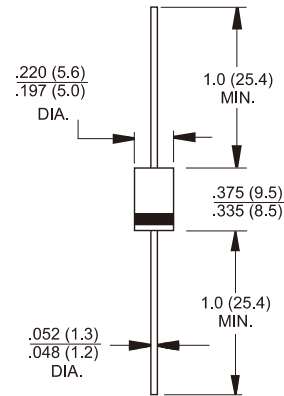


MUR420 - MUR460

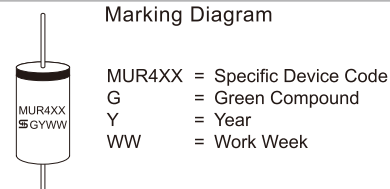
4.0 AMPS. Ultrafast Glass Passivated Rectifiers

DO-201AD



Dimensions in inches and (millimeters)

Marking Diagram



Features

- ✧ Ideally suited for use in very high frequency switching power supplies, inverters and as free wheeling diodes
- ✧ Ultrafast recovery time for high efficiency
- ✧ Excellent high temperature switching
- ✧ Glass passivated junction
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode.

Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode
- ✧ High temperature soldering guaranteed: 260°C/10 seconds/.375" (9.5mm) lead lengths at 5 lbs. (2.3kg) tension
- ✧ Mounting position: Any
- ✧ Weight: 1.20 grams

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MUR420	MUR440	MUR460	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	200	400	600	V
Maximum RMS Voltage	V_{RMS}	140	280	420	V
Maximum DC Blocking Voltage	V_{DC}	200	400	600	V
Maximum Average Forward Rectified Current .375" (9.5mm) Lead Length (See Fig. 1)	$I_F(AV)$	4.0			A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	125	70		A
Maximum Instantaneous Forward Voltage @ 4.0A	V_F	0.89	1.28		V
Maximum DC Reverse Current @ $T_A=25^\circ C$ at Rated DC Blocking Voltage @ $T_A=125^\circ C$ (Note 1)	I_R	5.0 150	10 250		μA μA
Maximum Reverse Recovery Time (Note 2)	T_{rr}	25	50		nS
Typical Junction Capacitance (Note 3) $T_J = 25^\circ C$ (Fig. 5)	C_j	65			pF
Maximum Forward Recovery Time T_{fr} ($I_F=1.0A$, $di/dt = 100A/\mu s$, Rev. to 1.0V)	T_{fr}	25	50		nS
Typical Thermal Resistance (Note 4)	$R_{\theta JA}$	28			$^\circ C/W$
Operating Temperature Range	T_J	-65 to +150			$^\circ C$
Storage Temperature Range	T_{STG}	-65 to +150			$^\circ C$

Notes: 1. Pulse test: $t_p = 300 \mu s$, Duty Cycle $< 1\%$.

2. Reverse Recovery Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $I_{RR}=0.25A$

3. Measured at 1 MHz and Applied Reverse Voltage of 4.0 Volts D.C.

4. Thermal Resistance from Junction to Ambient, Lead Length = 1/2" on P.C. Board with 0.6" x 0.6" Copper Surface.

RATINGS AND CHARACTERISTIC CURVES (MUR420 THRU MUR460)

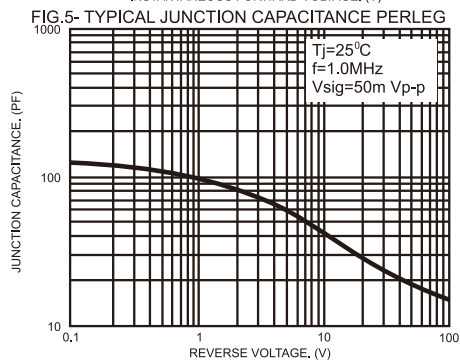
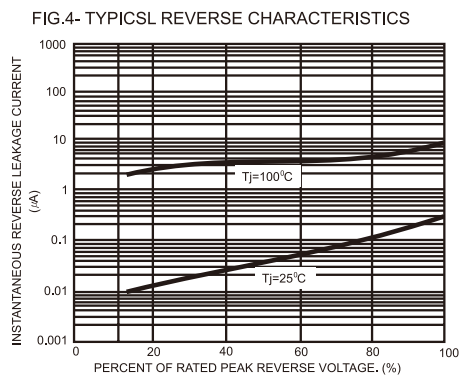
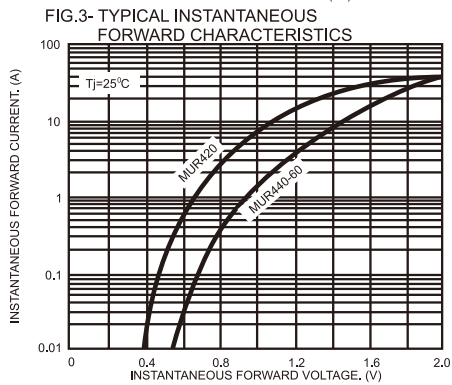
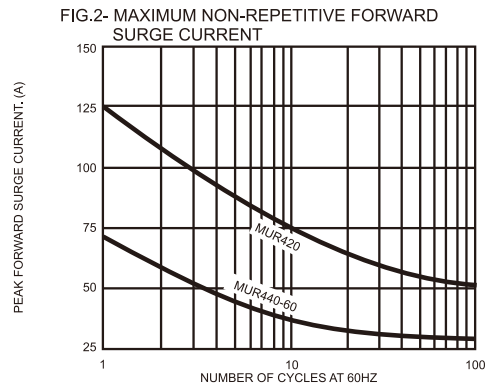
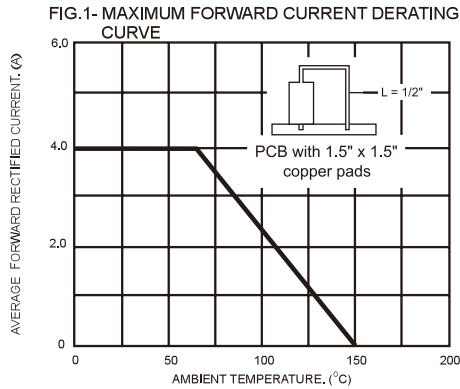


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

